

Experimental Demonstration at 10Gbit/s of a 2R-Regenerator based on the Mutual Optical Feedback between a Laser Diode and an SOA

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Abstract: A new regenerator concept based on the feedback between a laser diode and an SOA has been tested using an integrated version. Excellent regenerator characteristics, both static and 10Gbit/s dynamic operation, have been obtained.

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1. Introduction

All-optical regenerators could be a key building block of future all-optical networks. The key properties for a good all-optical regenerator are high-speed operation combined with a steep decision characteristic. Several regeneration schemes have already been proposed [1,2]. Most of them are based on the use of semiconductor optical amplifiers based interferometric set-ups. These schemes have the added advantage that they can easily be integrated on a single chip. It has however been shown that it is difficult to obtain both high-speed operation [3,4], bitrate independent operation and a steep decision characteristic [5,6] with the same component.

Earlier we presented a new type of regenerator [7,8] that gives a steep decision characteristic without making use of interferometric structures. The regenerator is based on an SOA in a feedback scheme with a DFB-laser.

In this paper we present measurement results of the static and dynamic performance of this scheme. The measurements were performed on a component, meant as a wavelength-selectable laser diode [9], but especially suited also for our purpose. We show a very steep optical decision characteristic combined with high-speed operation. Since there is no interference involved in obtaining the optical decision characteristic the regenerator can be used over a wide wavelength region and is very stable against environmental changes.

2. Principle of operation

A schematic of the regenerator is shown in Fig. 1. The light coming from the SOA is partly coupled into the laser diode. The same fraction of the laser light is coupled back into the SOA. The part of the output power that is not coupled to the laser diode is coupled out. Simulations and measurements on a set-up consisting of a discrete SOA and laser diode showed a very steep static transfer function [7,8]. Since we use here an integrated version of the regenerator the roundtrip time needed for the feedback is reduced significantly.

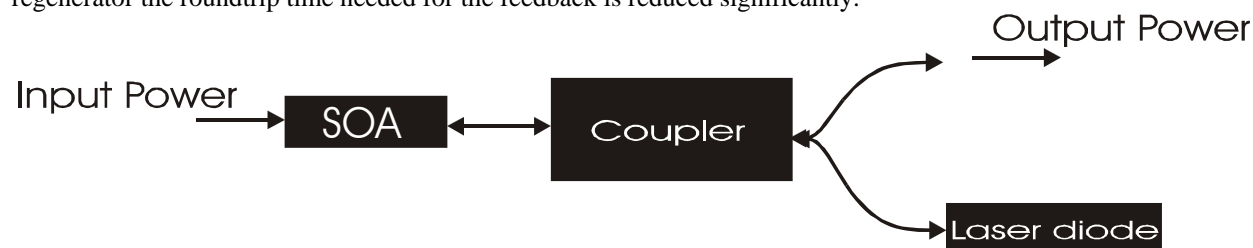


Fig. 1: Schematic of a semiconductor laser integrated with an SOA

In the experiments shown here we used a wavelength-selectable laser. In Fig. 2 a schematic representation of this device is given. It consists of an SOA that is connected to four laser diodes by means of a 1 by 4-coupler. Normally the light is coupled from lasers to SOA. In our case light is injected into the SOA and coupled out at the

back facet of one of the lasers. One can already notice two distinct differences with the originally simulated and measured device. The coupling between laser diode and SOA is smaller which leads to less feedback and the output light has to pass through the laser before being measured.

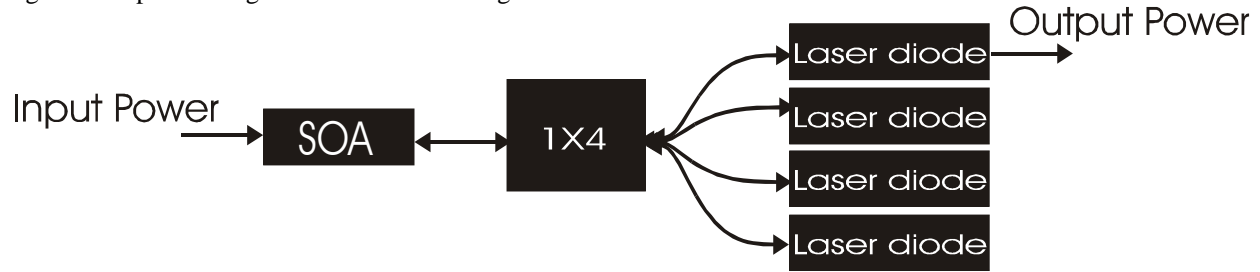


Fig. 2: Schematic of the wavelength-selectable laser used as regenerator

3. Static measurements

As a first step to experimentally characterise the new regenerator concept using the wavelength-selectable laser the static response has been studied. Light coming from a tunable laser source operating at a wavelength of 1553nm is coupled into the component using a lensed fiber. At the back facet of the pumped laser diode operating at a wavelength of 1545nm the light is coupled out again using a lensed fiber.

In Fig. 3 a decision characteristic is shown on which one can clearly see a step of about 5dB in output power over an input power range of less than 1dB. The relatively low output power can be caused by the fact that the light is coupled out at the back facet of the component. This back facet has not been designed for optimal coupling but as a mirror for the laser diodes in its original purpose.

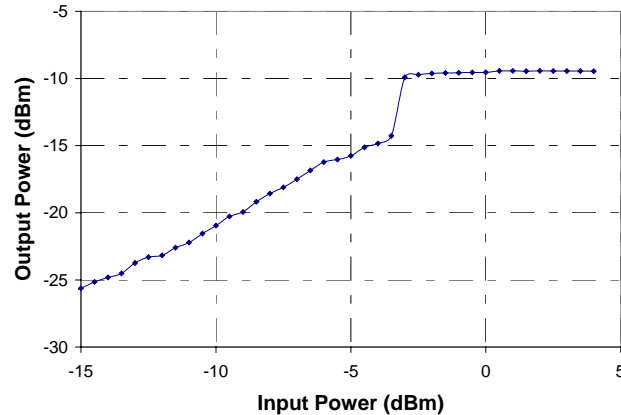


Fig. 3: Measured decision characteristic

4. Dynamic measurements at 10Gbit/s

In a next step dynamic measurements at 10 Gbit/s have been performed. The data signal is generated by modulating light from a tunable laser at a wavelength of 1555nm, with a PRBS of word length $2^{31}-1$. Before coupling to the component using a lensed fiber the light is sent through an EDFA, an attenuator and a 90/10 splitter. The EDFA and attenuator are used to control the power and quality of the light coupled into the component. The 10% fraction is used to monitor the input signal simultaneously with the output signal. At the back facet the light is again coupled out of the component using a lensed fiber. This signal is detected using a pre-amplified receiver.

In Fig. 4 input and output eye-diagrams at 10 Gbit/s are shown. It can be seen that an output extinction ratio of 10.3dB was obtained for an input extinction ratio of 3.4dB. The input eye diagram was measured after the 90/10 splitter and with an extra attenuation of 6dB resulting in a total attenuation of 16dB. The output eye diagram was measured with an attenuation of the input power of 14dB. Taking these attenuations into account one can see that the powers in the eye diagrams show good agreement with the difference between input and output power of the decision characteristic shown in Fig. 3.

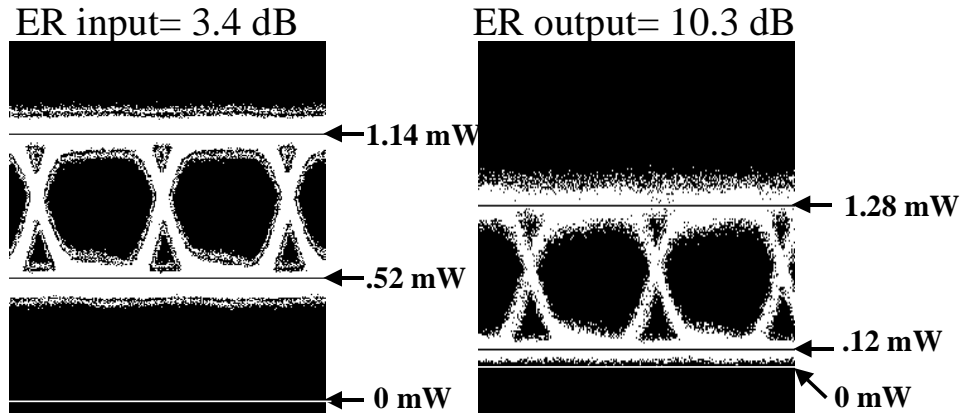


Fig. 4: Input and output eye diagrams

5. Conclusion

We have shown static and dynamic measurement results of an implementation with existing components of a regenerator based on the mutual optical feedback between a laser diode and an SOA. The static measurement shows a very steep transfer function. The dynamic measurements show extinction ratio improvement up to 6.9 dB at 10Gbit/s.

The circuit has a very simple structure and requires very little control. Moreover, since there is no interference involved the decision characteristic can be obtained over a wide wavelength range.

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